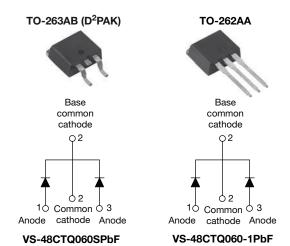


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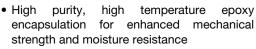
High Performance Schottky Rectifier, 2 x 20 A



PRODUCT SUMMARY	
Package	TO-263AB (D ² PAK), TO-262AA
I _{F(AV)}	2 x 20 A
V_R	60 V
V _F at I _F	0.58 V
I _{RM} max.	89 mA at 125 °C
T _J max.	150 °C
Diode variation	Common cathode
E _{AS}	13

FEATURES

- 150 °C T_J operation
- Center tap configuration
- Low forward voltage drop
- · High frequency operation





ROHS COMPLIANT HALOGEN FREE

- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

This center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform	40	Α		
V_{RRM}		60	V		
I _{FSM}	t _p = 5 μs sine	1000	Α		
V _F	20 A _{pk} , T _J = 125 °C (per leg)	0.58	V		
T _J	Range	-55 to +150	°C		

VOLTAGE RATINGS					
PARAMETER SYMBOL VS-48CTQ060SPbF UNITS					
Maximum DC reverse voltage	V_{R}	60	V		
Maximum working peak reverse voltage	V_{RWM}	00	V		

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	VALUES	UNITS				
Maximum average per leg		50.0/ duty evals at T = 111.9/	C rootongular wayafarm	20		
forward current, see fig. 5 per device	I _{F(AV)} 50 % duty cycle at T _C = 111 °C, rectangular waveform	o, rectangular wavelonn	40			
Maximum peak one cycle non-repetitive		5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	1000	Α	
surge current per leg, see fig. 7	IFSM	10 ms sine or 6 ms rect. pulse		260		
Non-repetitive avalanche energy per leg	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 1.50 \text{A}, L = 1.50 \text{A}$	1.5 mH	13	mJ	
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to ze Frequency limited by T _J maxin		1.50	Α	



VS-48CTQ060SPbF, VS-48CTQ060-1PbF

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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS
		20 A	T _ 25 °C	0.61	
Maximum forward voltage drop per leg See fig. 1	V _{FM} ⁽¹⁾	40 A	T _J = 25 °C	0.83	V
	VFM ('')	20 A	T _{.1} = 125 °C	0.58	
		40 A	- IJ = 125 C	0.75	
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	2	mΛ
See fig. 2	'RM '''	T _J = 125 °C	v _R = nateu v _R	89	mA
Threshold Voltage	V _{F(TO)}	T. T. mavimum		0.37	V
Forward slope resistance	r _t	T _J =T _J maximum		8.26	mΩ
Maximum junction capacitance per leg	C _T	V _R = 5 V _{DC} (test signal ran	ge 100 kHz to 1 MHz), 25 °C	1220	pF
Typical series inductance per leg	L _S	Measured lead to lead 5 m	nm from package body	8.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs

Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHAN	THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range		T _J , T _{Stg}		-55 to +150	°C
Maximum thermal resistance, junction to case per leg		R _{thJC}	DC operation	2.0	
Maximum thermal resistance, junction to case per package Typical thermal resistance, case to heatsink		□thJC	Do operation	1.0	°C/W
		R _{thCS}	Mounting surface, smooth and greased	0.50	
Approximate weight				2	g
Approximate weight				0.07	OZ.
Mounting torque minimum				6 (5)	kgf · cm
Mounting torque	maximum			12 (10)	(lbf \cdot in)
Marking daying			Case style TO-263AB (D2PAK)	48CT0	Q060S
Marking device			Case style TO-262AA	48CTC	2060-1

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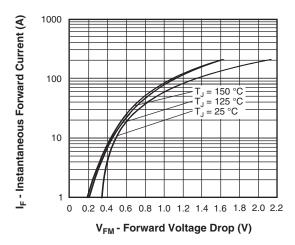


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

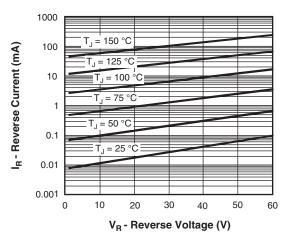


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

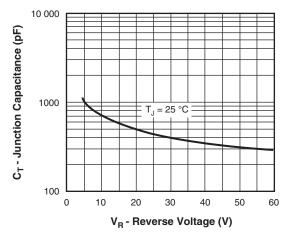


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

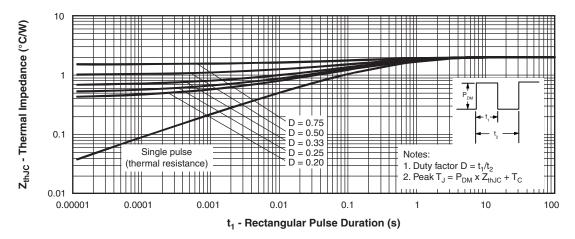


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)

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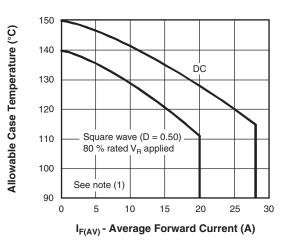


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

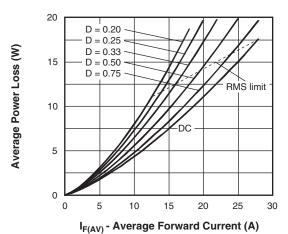


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

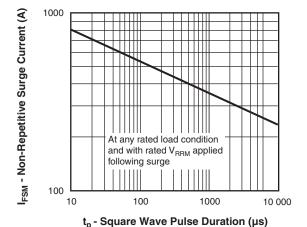


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

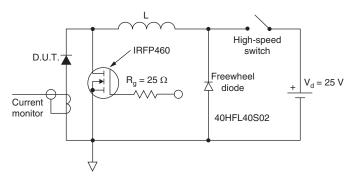


Fig. 8 - Unclamped Inductive Test Circuit

Note

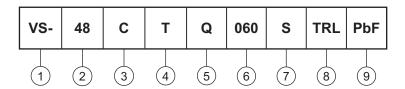
 $^{(1)}$ Formula used: $T_C = T_J$ - (Pd + Pd_{REV}) x R_{thJC}; Pd = Forward power loss = $I_{F(AV)}$ x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 10 V

VS-48CTQ060SPbF, VS-48CTQ060-1PbF

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

- Current rating (40 A)

Circuit configuration: C = common cathode

4 - T = TO-220

5 - Schottky "Q" series

6 - Voltage rating (060 = 60 V)

7 - • S = D²PAK

• -1 = TO-262

8 - • None = tube (50 pieces)

• TRL = tape and reel (left oriented - for D²PAK only)

• TRR = tape and reel (right oriented - for D²PAK only)

9 - PbF = lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N QUANTITY PER REEL MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION						
VS-48CTQ060SPBF	50	1000	Antistatic plastic tubes			
VS-48CTQ060STRRPBF	800	800	13" diameter plastic tape and reel			
VS-48CTQ060STRLPBF	800	800	13" diameter plastic tape and reel			
VS-48CTQ060-1PBF	50	1000	Antistatic plastic tubes			

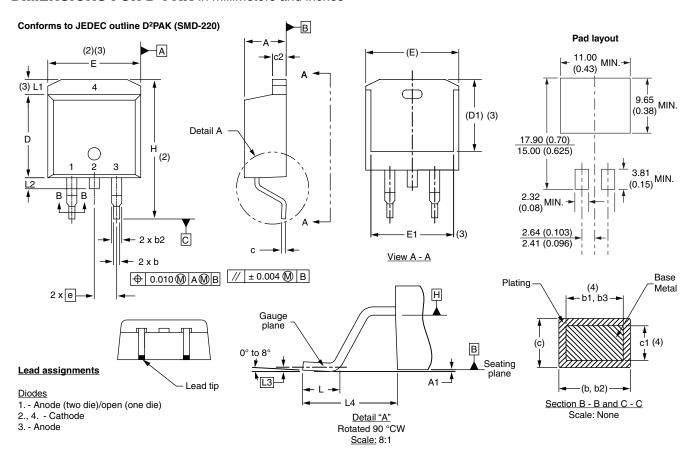
LINKS TO RELATED DOCUMENTS				
		www.vishay.com/doc?95046		
Dimensions	TO-262AA	www.vishay.com/doc?95419		
Part marking information		www.vishay.com/doc?95008		
Packaging information		www.vishay.com/doc?95032		



Vishay High Power Products

D²PAK, TO-262

DIMENSIONS FOR D²PAK in millimeters and inches



0.44501	MILLIM	IETERS	INC	HES	
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25	BSC	0.010	BSC	
L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- $^{(3)}\,$ Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch

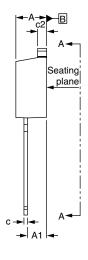
(7) Outline conforms to JEDEC outline TO-263AB

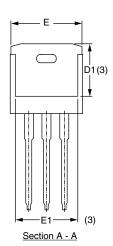
Vishay High Power Products

D²PAK, TO-262



DIMENSIONS FOR TO-262 in millimeters and inches





⊕ 0.010**⋒**|A**⋒**|B

Lead assignments

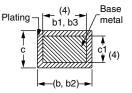


<u>Diodes</u>

-3 x b2 --3 x b

> 1. - Anode (two die)/open (one die) 2., 4. - Cathode

3. - Anode



Section B - B and C - C Scale: None

OVMBOL	MILLIMETERS		INC	CHES	NOTES
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.10	0 BSC	
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Controlling dimension: inches

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline



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Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

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